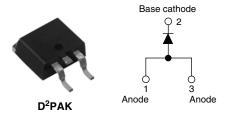


Vishay High Power Products

Input Rectifier Diode, 10 A



PRODUCT SUMMARY					
V _F at 10 A	< 1 V				
I _{FSM}	200 A				
V _{RRM}	800 V/1200 V				

DESCRIPTION/FEATURES

The VS-10ETS..SPbF rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

Typical applications are in input rectification and these products are designed to be used with Vishay HPP switches and output rectifiers which are available in identical package outlines.



- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\mathrm{C}$
- Compliant to RoHS directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Designed and qualified for industrial level

OUTPUT CURRENT IN TYPICAL APPLICATIONS									
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS									
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W	12.0	16.0	А						

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Sinusoidal waveform	10	A						
V _{RRM}		800/1200	V						
I _{FSM}		200	A						
V _F	10 A, T _J = 25 °C	1.1	V						
TJ		- 40 to 150	°C						

VOLTAGE RATINGS										
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA							
VS-10ETS08SPbF	800	900								
VS-10ETS10SPbF	1000	1100	0.5							
VS-10ETS12SPbF	1200	1300								

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I _{F(AV)}	T_{C} = 105 °C, 180° conduction half sine wave	10						
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	170	А					
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	200						
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	130	A ² s					
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	145						
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1450	A²√s					

VS-10ETS..SPbF High Voltage Series

Vishay High Power Products Input Rectifier Diode, 10 A



ELECTRICAL SPECIFICATIONS									
PARAMETER	VALUES	UNITS							
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C	1.1	V					
Forward slope resistance	r _t	T.I = 150 °C		20	mΩ				
Threshold voltage	V _{F(TO)}	$I_{\rm J} = 150$ C		0.82	V				
	1	T _J = 25 °C	V - Reted V	0.05	m۸				
Maximum reverse leakage current	IRM	T _J = 150 °C	$V_{R} = Rated V_{RRM}$	0.50	mA				

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 150	°C					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W					
Maximum thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	0/11					
Soldering temperature	Τs		240	°C					
Approximate weight			2	g					
Approximate weight			0.07	oz.					
			10ET	S08S					
Marking device		Case style D ² PAK (SMD-220)	10ETS10S						
			10ET	S12S					

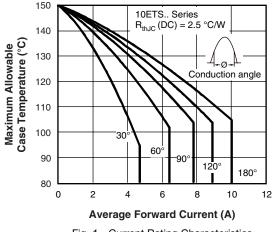
Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994



VS-10ETS..SPbF High Voltage Series

Input Rectifier Diode, 10 A Vishay High Power Products





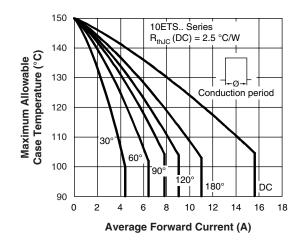


Fig. 2 - Current Rating Characteristics

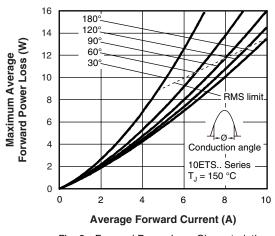
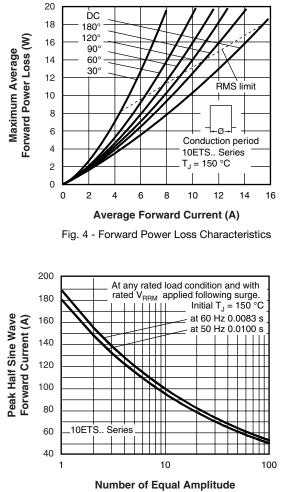


Fig. 3 - Forward Power Loss Characteristics



Half Cycle Current Pulses (N) Fig. 5 - Maximum Non-Repetitive Surge Current

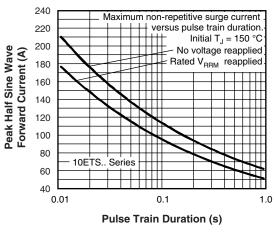


Fig. 6 - Maximum Non-Repetitive Surge Current

VS-10ETS..SPbF High Voltage Series

Vishay High Power Products Input Rectifier Diode, 10 A



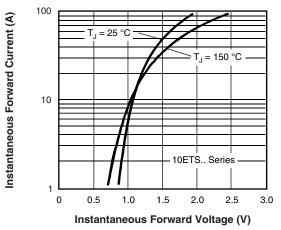


Fig. 7 - Forward Voltage Drop Characteristics

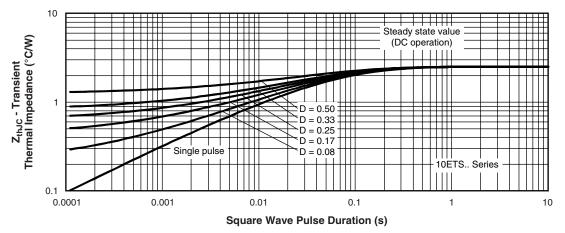


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



Input Rectifier Diode, 10 A Vishay High Power Products

ORDERING INFORMATION TABLE

Device code	vs-	10	Е	т	S	12	S	TRL	PbF	
		2	3	4	5	6	7	8	9	
	 HPP product suffix Current rating (10 = 10 A) Circuit configuration: 									
	4 - 5 -	E = Single diode - Package: T = TO-220AC - Type of silicon:								
	6 - 7 - 8 -	$S = Standard recovery rectifier$ $Voltage code x 100 = V_{RRM} \qquad 08 = 800 V$ $10 = 1000 V$ $12 = 1200 V$ $Voltage Tube$								
	9 -	• TI • TI	RL = Ta RR = Ta	pe and r pe and r (Pb)-fre	reel (rig		-			

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95046						
Part marking information	www.vishay.com/doc?95054						
Packaging information	www.vishay.com/doc?95032						

Outline Dimensions

Vishay Semiconductors

D²PAK



Conforms to JEDEC outline D²PAK (SMD-220) в Pad layout (2)(3)A 11.00 MIN.-(E) F (0.43)ŧ (3) L1 4 (|(0.38)^{MIN.} (D1) (3) Detail A D 17.90 (0.70) Н 15.00 (0.625) (2) З 0.15)^{0.01} Ľ L2 Ĥ ţ В В 2.32 MIN. (0.08) 2.64 (0.103) 2.41 (0.096) (3)Ċ 2 x b2 С View A - A 2 x h // ± 0.004 M B ⊕ 0.010 M A M B Base Plating (4) Metal 2 x e Н b1, b3 Gauge plane c1 (4) (c) В 0° to 8° ŧ. Seating Lead assignments plane L3 A1 Lead tip (b, b2) Diodes Section B - B and C - C 1. - Anode (two die)/open (one die) Scale: None 2., 4. - Cathode Detail "A" 3. - Anode

Rotated 90 °CW Scale: 8:1

SYMBOL	MILLIMETERS		INCHES		NOTES		INCHES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3		
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3		
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3		
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC			
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625			
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110			
с	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3		
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070			
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC			
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208			

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

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DIMENSIONS in millimeters and inches



Vishay

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